

Schottky Diode Array for Four Data Line ESD Protection

NUP4302MR6

The NUP4302MR6 is designed to protect high speed data line interface from ESD, EFT and lighting.

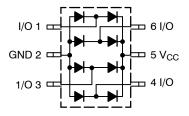
Features

- Very Low Forward Voltage Drop
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection
- ESD Rating of Class 3B (Exceeding 16 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model
- IEC 61000-4-2 Level 4 ESD Protection
- Flammability Rating: UL 94 V-0
- Pb-Free Package is Available

Applications

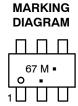
- Ultra High-Speed Switching
- USB 1.1 and 2.0 Power and Data Line Protection
- Digital Video Interface (DVI)
- Monitors and Flat Panel Displays

PIN CONFIGURATION AND SCHEMATIC





TSOP-6 CASE 318G STYLE 12



67 = Specific Device Code M = Date Code

M = Date Code■ Pb-Free Package

(Note: Microdot may be in either location)

 Date Code orientation may vary depending upon manufacturing location

ORDERING INFORMATION

Device	Package	Shipping [†]
NUP4302MR6T1G	TSOP-6 (Pb-Free)	3000/Tape & Reel

DISCONTINUED (Note 1)

1

NUP4302MR6T1	TSOP-6	3000/Tape & Reel

- † For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.
- DISCONTINUED: This device is not available. Please contact your onsemi representative for information. The most current information on this device may be available on www.onsemi.com.

NUP4302MR6

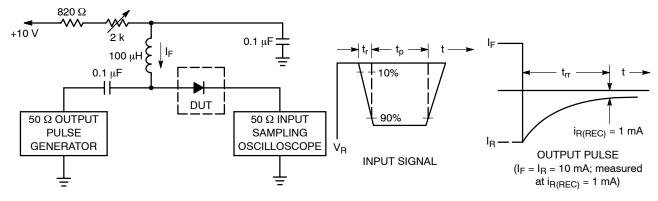
MAXIMUM RATINGS ($T_J = 25$ °C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Reverse Breakdown Voltage	V_{BR}	30	V
Forward Power Dissipation (T _A = 25 °C)	P _F	225	mW
Forward Continuous Current	IF	200	mA
Junction Operating Temperature	TJ	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS (T_J = 25 °C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Breakdown Voltage	V_{BR}	I _R = 100 μA	30			V
Reverse Leakage	I _R	V _R = 25 V			30	μΑ
Forward Voltage	V _F	I _F = 0.1 mAdc			0.28	V
Forward Voltage	V _F	I _F = 1.0 mAdc			0.35	V
Forward Voltage	V _F	I _F = 10 mAdc			0.45	V
Forward Voltage $V_F = I_F = 100 \text{ mAc}$		I _F = 100 mAdc			1.00	V
Total Capacitance C _T		V_R = 0 V, f = 1.0 MHz, I/O to Ground V_R = 0 V, f = 1.0 MHz, I/O to I/O			28 18	pF
Reverse Recovery Time	t _{rr}	$I_F = I_R = 10 \text{ mA}, I_{R(REC)} = 1.0 \text{ mA (Figure 1)}$			5.0	ns



Notes: 1. A 2.0 $k\Omega$ variable resistor adjusted for a Forward Current (I_F) of 10 mA.

- 2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 10 mA.
- 3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

NUP4302MR6

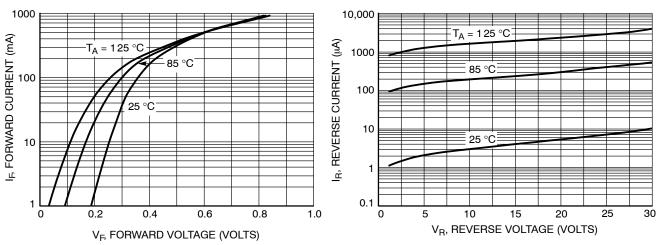


Figure 2. Forward Current as a Function of Forward Voltage; Typical Values

Figure 3. Reverse Current as a Function of Reverse Voltage; Typical Values

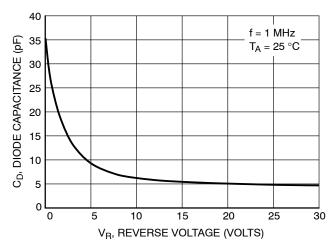


Figure 4. Diode Capacitance as a Function of Reverse Voltage; Typical Values

NUP4302MR6

REVISION HISTORY

I	Revision	Description of Changes	Date
	4	Document rebranded to onsemi format. NUP4302MR6T1 OPN marked as discontinued.	11/18/2025

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.





NOTE 5

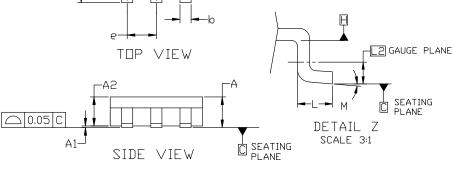
TSOP-6 3.00x1.50x0.90, 0.95P **CASE 318G ISSUE W**

DATE 26 FEB 2024

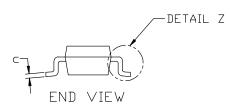


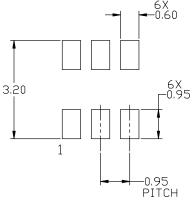
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.

 5. PIN 1 INDICATOR MUST BE LOCATED IN THE INDICATED ZONE



N	1ILLIM	IETERS	2
DIM	MIN	NDM	MAX
Α	0.90	1.00	1.10
A1	0.01	0.06	0.10
A2	0.80	0.90	1.00
b	0.25	0.38	0.50
C	0.10	0.18	0.26
D	2.90	3.00	3,10
Е	2.50	2.75	3.00
E1	1.30	1.50	1.70
е	0.85	0.95	1.05
L	0.20	0.40	0.60
L2	0.25 BSC		
М	0°		10°





RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference manual, SDLDERRM/D.

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DESCRIPTION:	TSOP-6 3.00x1.50x0.90, 0.	95P	PAGE 1 OF 2

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TSOP-6 3.00x1.50x0.90, 0.95P CASE 318G

ISSUE W

DATE 26 FEB 2024

GENERIC MARKING DIAGRAM*



XXX M=

O =

1 U U

STANDARD

XXX = Specific Device Code

XXX = Specific Device Code

A =Assembly Location

M = Date Code

Y = Year

■ = Pb-Free Package

W = Work Week

vveek

■ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SOURCE 5. DRAIN 6. DRAIN	STYLE 2: PIN 1. EMITTER 2 2. BASE 1 3. COLLECTOR 1 4. EMITTER 1 5. BASE 2 6. COLLECTOR 2	STYLE 3: PIN 1. ENABLE 2. N/C 3. R BOOST 4. Vz 5. V in 6. V out	STYLE 4: PIN 1. N/C 2. V in 3. NOT USED 4. GROUND 5. ENABLE 6. LOAD	STYLE 5: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 6: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR
STYLE 7: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. N/C 5. COLLECTOR 6. EMITTER	STYLE 8: PIN 1. Vbus 2. D(in) 3. D(in)+ 4. D(out)+ 5. D(out) 6. GND	STYLE 9: PIN 1. LOW VOLTAGE GATE 2. DRAIN 3. SOURCE 4. DRAIN 5. DRAIN 6. HIGH VOLTAGE GATE	2. GND ' 3. D(OUT)- 4. D(IN)- 5. VBUS	STYLE 11: PIN 1. SOURCE 1 2. DRAIN 2 3. DRAIN 2 4. SOURCE 2 5. GATE 1 6. DRAIN 1/GATE 2	STYLE 12: PIN 1. I/O 2. GROUND 3. I/O 4. I/O 5. VCC 6. I/O
STYLE 13: PIN 1. GATE 1 2. SOURCE 2 3. GATE 2 4. DRAIN 2 5. SOURCE 1 6. DRAIN 1	STYLE 14: PIN 1. ANODE 2. SOURCE 3. GATE 4. CATHODE/DRAIN 5. CATHODE/DRAIN 6. CATHODE/DRAIN	PIN 1. ANODE PI 2. SOURCE 3. GATE 4. DRAIN	LE 16: N 1. ANODE/CATHODE 2. BASE 3. EMITTER 4. COLLECTOR 5. ANODE 6. CATHODE	STYLE 17: PIN 1. EMITTER 2. BASE 3. ANODE/CATHODE 4. ANODE 5. CATHODE 6. COLLECTOR	

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